

# Voltage Regulator - Low-Drop, Reset

450 mA

## NCV4275C

The NCV4275C is an integrated low dropout regulator designed for use in harsh automotive environments. It includes wide operating temperature and input voltage ranges. The output is regulated at 5.0 V or 3.3 V and is rated to 450 mA of output current. It also provides a number of features, including overcurrent protection, overtemperature protection and a programmable microprocessor reset. The NCV4275C is available in the DPAK and D<sup>2</sup>PAK surface mount packages. The output is stable over a wide output capacitance and ESR range. The NCV4275C is pin for pin compatible with NCV4275A.

### Features

- 5.0 V or 3.3 V  $\pm 2\%$  Output Voltage Options
- 450 mA Output Current
- Very Low Current Consumption
- Active Reset Output
- Reset Low Down to  $V_Q = 1.0$  V
- 500 mV (max) Dropout Voltage
- Fault Protection
  - ♦ +45 V Peak Transient Voltage
  - ♦ -42 V Reverse Voltage
  - ♦ Short Circuit Protection
  - ♦ Thermal Overload Protection
- AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

### Applications

- Auto Body Electronics

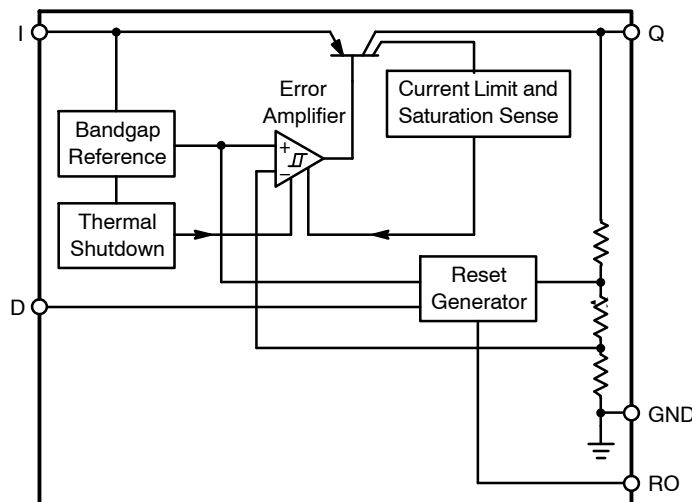
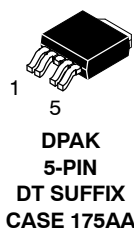
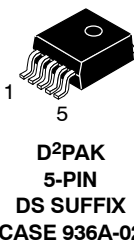
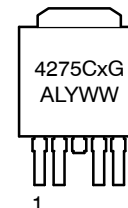


Figure 1. Block Diagram



### MARKING DIAGRAMS



|       |                                           |
|-------|-------------------------------------------|
| x     | = 5 (5.0 V Output)<br>or 3 (3.3 V Output) |
| A     | = Assembly Location                       |
| WL, L | = Wafer Lot                               |
| Y     | = Year                                    |
| WW    | = Work Week                               |
| G     | = Pb-Free Package                         |

### ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 13.

## PIN FUNCTION DESCRIPTION

| Pin No.           | Symbol | Description                                                                                                                              |
|-------------------|--------|------------------------------------------------------------------------------------------------------------------------------------------|
| DPAK-5<br>D2PAK-5 |        |                                                                                                                                          |
| 1                 | I      | Input; Battery Supply Input Voltage. Bypass to ground with a ceramic capacitor.                                                          |
| 2                 | RO     | Reset Output; Open Collector Active Reset (accurate when I > 1.0 V).                                                                     |
| 3, TAB            | GND    | Ground; Pin 3 internally connected to tab.                                                                                               |
| 4                 | D      | Reset Delay; timing capacitor to GND for Reset Delay function.                                                                           |
| 5                 | Q      | Output; $\pm 2.0\%$ , 450 mA output. Bypass with 22 $\mu$ F capacitor, ESR < 4.5 $\Omega$ (5.0 V Version), 3.5 $\Omega$ (3.3 V Version). |

## MAXIMUM RATINGS

| Rating                       | Symbol             | Min                | Max  | Unit |
|------------------------------|--------------------|--------------------|------|------|
| Input Voltage                | $V_I$              | -42                | 45   | V    |
| Input Peak Transient Voltage | $V_I$              | -                  | 45   | V    |
| Output Voltage               | $V_Q$              | -1.0               | 16   | V    |
| Reset Output Voltage         | $V_{RO}$           | -0.3               | 25   | V    |
| Reset Output Current         | $I_{RO}$           | -5.0               | 5.0  | mA   |
| Reset Delay Voltage          | $V_D$              | -0.3               | 7.0  | V    |
| Reset Delay Current          | $I_D$              | -2.0               | 2.0  | mA   |
| ESD Susceptibility (Note 1)  | - Human Body Model | ESD <sub>HBM</sub> | 4.0  | kV   |
| - Machine Model              |                    | ESD <sub>MM</sub>  | 200  | V    |
| - Charge Device Model        |                    | ESD <sub>CDM</sub> | 1000 | V    |
| Junction Temperature         | $T_J$              | -40                | 150  | °C   |
| Storage Temperature          | $T_{stg}$          | -55                | 150  | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. Operating the device outside its recommended conditions, but still within its maximum rated limits may not cause immediate damage. However, doing so can lead to reduced performance, unpredictable behavior, and potentially shorten the device's lifespan or reliability.

1. This device incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002, ESD Machine Model tested per AEC-Q100-003, ESD Charged Device Model tested per AEC-Q100-011, Latch-up tested per AEC-Q100-004.

## OPERATING RANGE

| Rating                                      | Symbol | Min | Max | Unit |
|---------------------------------------------|--------|-----|-----|------|
| Input Voltage Operating Range, 5.0 V Output | $V_I$  | 5.5 | 42  | V    |
| Input Voltage Operating Range, 3.3 V Output | $V_I$  | 4.4 | 42  | V    |
| Junction Temperature                        | $T_J$  | -40 | 150 | °C   |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## LEAD TEMPERATURE SOLDERING REFLOW AND MSL (Note 2)

| Rating                                 | Symbol    | Min | Max      | Unit |
|----------------------------------------|-----------|-----|----------|------|
| Lead Free, 60 sec-150 sec above 217 °C | $T_{SLD}$ | -   | 265 Peak | °C   |
| Moisture Sensitivity Level             | MSL       | 1   |          |      |



**THERMAL CHARACTERISTICS**

| Characteristic | Test Conditions (Typical Value) |  | Unit |
|----------------|---------------------------------|--|------|
|----------------|---------------------------------|--|------|

**DPAK 5-PIN PACKAGE**

|                                         | Min Pad Board (Note 3) | 1 in Pad Board (Note 4) |      |
|-----------------------------------------|------------------------|-------------------------|------|
| Junction-to-Tab ( $R_{\theta JT}$ )     | 5.1                    | 5.5                     | °C/W |
| Junction-to-Ambient ( $R_{\theta JA}$ ) | 82.4                   | 58.1                    | °C/W |

**D<sup>2</sup>PAK 5-PIN PACKAGE**

|                                         | 0.4 sq. in. Spreader Board (Note 5) | 1.2 sq. in. Spreader Board (Note 6) |      |
|-----------------------------------------|-------------------------------------|-------------------------------------|------|
| Junction-to-Tab ( $R_{\theta JT}$ )     | 4.5                                 | 4.8                                 | °C/W |
| Junction-to-Ambient ( $R_{\theta JA}$ ) | 66.0                                | 49.0                                | °C/W |

2.  $PR_R$  IPC / JEDEC J-STD-020C
3. 1 oz. copper, 0.26 inch<sup>2</sup> (168 mm<sup>2</sup>) copper area, 0.062" thick FR4.
4. 1 oz. copper, 1.14 inch<sup>2</sup> (736 mm<sup>2</sup>) copper area, 0.062" thick FR4.
5. 1 oz. copper, 0.373 inch<sup>2</sup> (241 mm<sup>2</sup>) copper area, 0.062" thick FR4.
6. 1 oz. copper, 1.222 inch<sup>2</sup> (788 mm<sup>2</sup>) copper area, 0.062" thick FR4.

# NCV4275C

## ELECTRICAL CHARACTERISTICS ( $V_I = 13.5\text{ V}$ ; $-40\text{ }^{\circ}\text{C} < T_J < 150\text{ }^{\circ}\text{C}$ ; unless otherwise noted.)

| Characteristic                         | Symbol          | Test Conditions                                                                                                                                                              | Min                 | Typ        | Max                 | Unit          |
|----------------------------------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|------------|---------------------|---------------|
| <b>Output</b>                          |                 |                                                                                                                                                                              |                     |            |                     |               |
| Output Voltage                         | $V_Q$           | $100\text{ }\mu\text{A} \leq I_Q \leq 400\text{ mA}$<br>$6.0\text{ V} \leq V_I \leq 28\text{ V}$ (5.0 V Version)<br>$4.4\text{ V} \leq V_I \leq 28\text{ V}$ (3.3 V version) | 4.9<br>3.23<br>(2%) | 5.0<br>3.3 | 5.1<br>3.37<br>(2%) | V             |
| Output Voltage                         | $V_Q$           | $100\text{ }\mu\text{A} \leq I_Q \leq 200\text{ mA}$<br>$6.0\text{ V} \leq V_I \leq 40\text{ V}$ (5.0 V Version)<br>$4.4\text{ V} \leq V_I \leq 40\text{ V}$ (3.3 V version) | 4.9<br>3.23<br>(2%) | 5.0<br>3.3 | 5.1<br>3.37<br>(2%) | V             |
| Output Current Limitation              | $I_Q$           | $V_Q = 0.9 \times V_{Q,\text{typ}}$                                                                                                                                          | 450                 | 650        | –                   | mA            |
| Quiescent Current<br>$I_q = I_I - I_Q$ | $I_q$           | $I_Q = 1.0\text{ mA}$ , $T_J = 25\text{ }^{\circ}\text{C}$                                                                                                                   | –                   | 135        | 150                 | $\mu\text{A}$ |
|                                        |                 | $I_Q = 1.0\text{ mA}$                                                                                                                                                        | –                   | 150        | 200                 | $\mu\text{A}$ |
|                                        |                 | $I_Q = 250\text{ mA}$                                                                                                                                                        | –                   | 10         | 15                  | mA            |
|                                        |                 | $I_Q = 400\text{ mA}$                                                                                                                                                        | –                   | 23         | 35                  | mA            |
| Dropout Voltage (Note 7)               | $V_{\text{dr}}$ | $I_Q = 300\text{ mA}$<br>$V_{\text{dr}} = V_I - V_Q$                                                                                                                         | –                   | 250        | 500                 | mV            |
| Load Regulation                        | $\Delta V_Q$    | $I_Q = 5.0\text{ mA}$ to $400\text{ mA}$                                                                                                                                     | –30                 | 15         | 30                  | mV            |
| Line Regulation                        | $\Delta V_Q$    | $\Delta V_I = 8.0\text{ V}$ to $32\text{ V}$ ,<br>$I_Q = 5.0\text{ mA}$                                                                                                      | –15                 | 5.0        | 15                  | mV            |
| Power Supply Ripple Rejection          | PSRR            | $f_r = 100\text{ Hz}$ , $V_r = 0.5\text{ V}_{\text{pp}}$                                                                                                                     | –                   | 60         | –                   | dB            |
| Temperature Output Voltage Drift       | $dV_Q/dT$       | ---                                                                                                                                                                          | –                   | 0.5        | –                   | mV/K          |

### Reset Timing D and Output RO

|                                                             |                   |                                                                                                 |          |          |          |                    |
|-------------------------------------------------------------|-------------------|-------------------------------------------------------------------------------------------------|----------|----------|----------|--------------------|
| Reset Switching Threshold<br>5.0 V Version<br>3.3 V Version | $V_{Q,\text{rt}}$ | $V_{\text{out}}$ decreasing<br>$V_{\text{in}} > 5.5\text{ V}$<br>$V_{\text{in}} > 4.4\text{ V}$ | 90<br>90 | 93<br>93 | 96<br>96 | % $V_{\text{out}}$ |
| Reset Output Low Voltage                                    | $V_{\text{ROL}}$  | $R_{\text{ext}} \geq 5.0\text{ k}\Omega$ , $V_Q \geq 1.0\text{ V}$                              | –        | 0.2      | 0.4      | V                  |
| Reset Output Leakage Current                                | $I_{\text{ROH}}$  | $V_{\text{ROH}} = 5.0\text{ V}$                                                                 | –        | 0        | 10       | $\mu\text{A}$      |
| Reset Charging Current                                      | $I_{\text{D,C}}$  | $V_D = 1.0\text{ V}$                                                                            | 3.0      | 5.5      | 9.0      | $\mu\text{A}$      |
| Upper Timing Threshold                                      | $V_{\text{DU}}$   | ---                                                                                             | 1.5      | 1.8      | 2.2      | V                  |
| Lower Timing Threshold                                      | $V_{\text{DL}}$   | ---                                                                                             | 0.2      | 0.4      | 0.7      | V                  |
| Reset Delay Time                                            | $t_{\text{rd}}$   | $C_D = 47\text{ nF}$                                                                            | 10       | 16       | 22       | ms                 |
| Reset Reaction Time                                         | $t_{\text{rr}}$   | $C_D = 47\text{ nF}$                                                                            | –        | 1.5      | 4.0      | $\mu\text{s}$      |

### Thermal Shutdown

|                               |                 |     |     |   |     |                    |
|-------------------------------|-----------------|-----|-----|---|-----|--------------------|
| Shutdown Temperature (Note 8) | $T_{\text{SD}}$ | --- | 150 | – | 210 | $^{\circ}\text{C}$ |
|-------------------------------|-----------------|-----|-----|---|-----|--------------------|

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Only for 5 V Version. Measured when the output voltage  $V_Q$  has dropped 100 mV from the nominal value obtained at  $V_I = 13.5\text{ V}$ .

8. Guaranteed by design, not tested in production.



TYPICAL PERFORMANCE CHARACTERISTICS

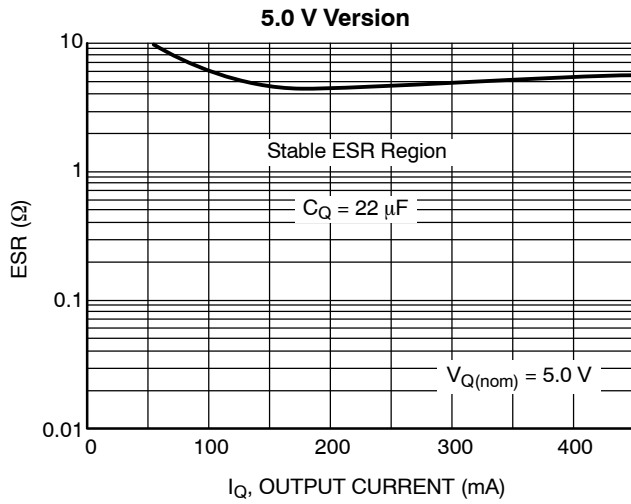


Figure 2. Output Stability with Output Capacitor ESR

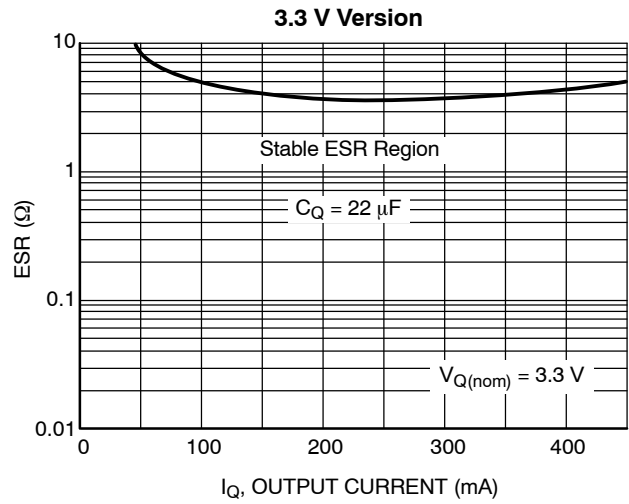


Figure 3. Output Stability with Output Capacitor ESR

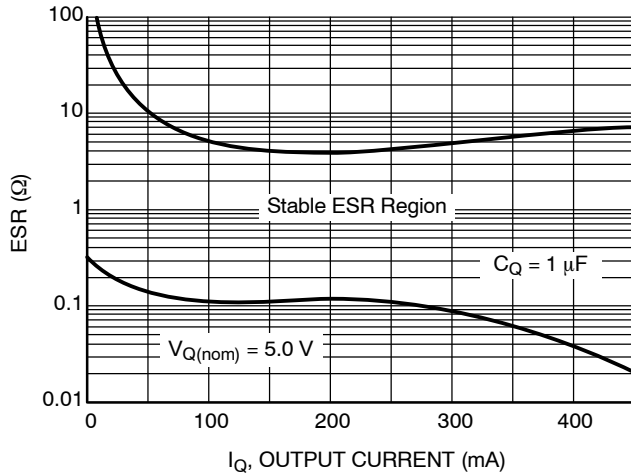


Figure 4. Output Stability with Output Capacitor ESR

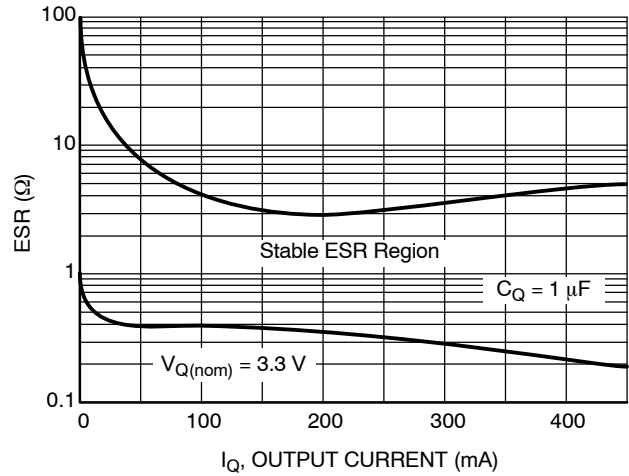


Figure 5. Output Stability with Output Capacitor ESR

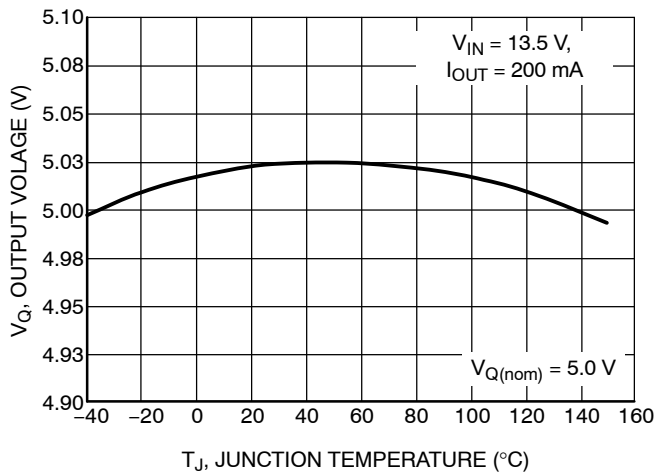


Figure 6. Output Voltage  $V_Q$  vs. Temperature  $T_J$

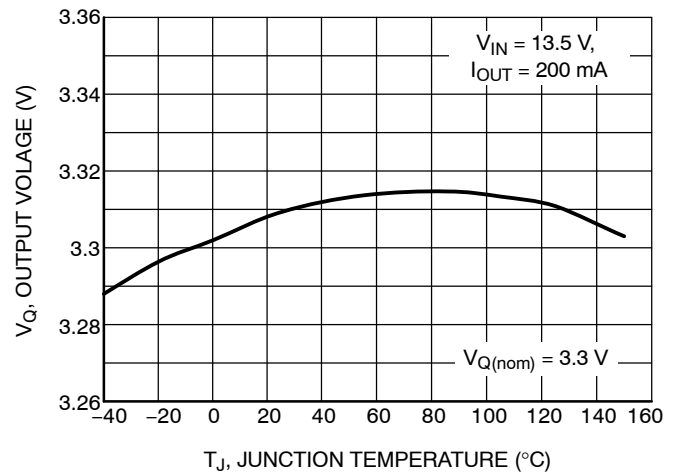


Figure 7. Output Voltage  $V_Q$  vs. Temperature  $T_J$

TYPICAL PERFORMANCE CHARACTERISTICS

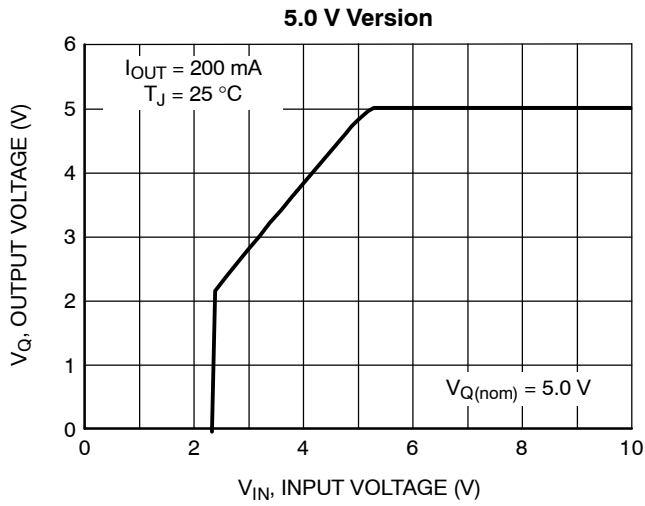


Figure 8. Output Voltage  $V_Q$  vs. Input Voltage  $V_{IN}$

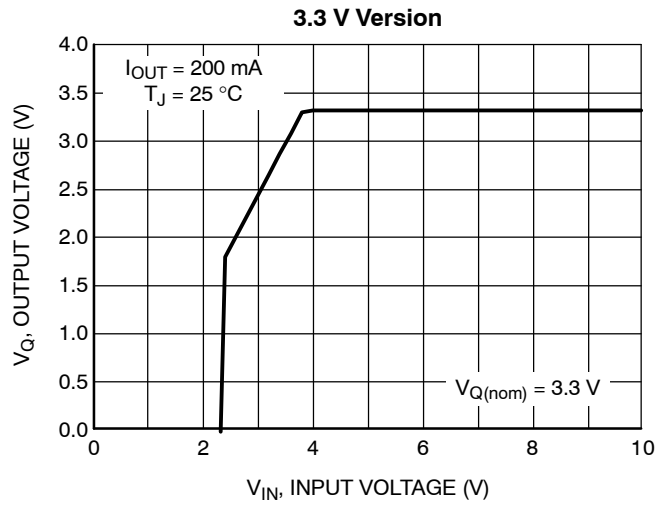


Figure 9. Output Voltage  $V_Q$  vs. Input Voltage  $V_{IN}$

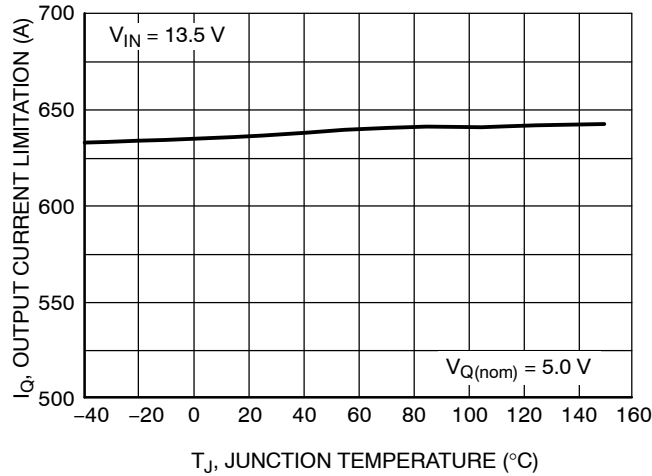


Figure 10. Output Current  $I_Q$  vs. Temperature  $T_J$

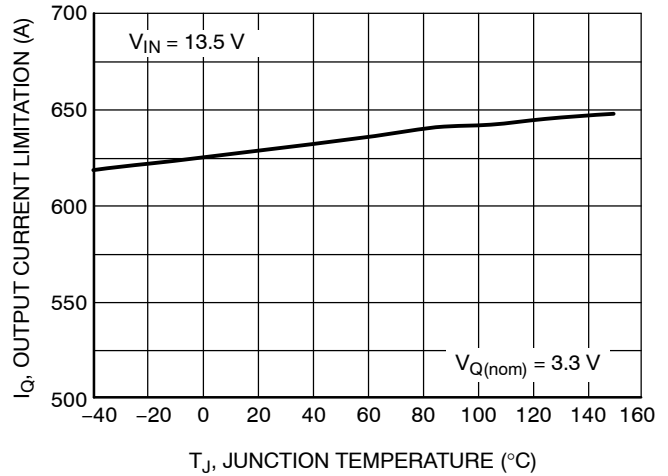


Figure 11. Output Current  $I_Q$  vs. Temperature  $T_J$

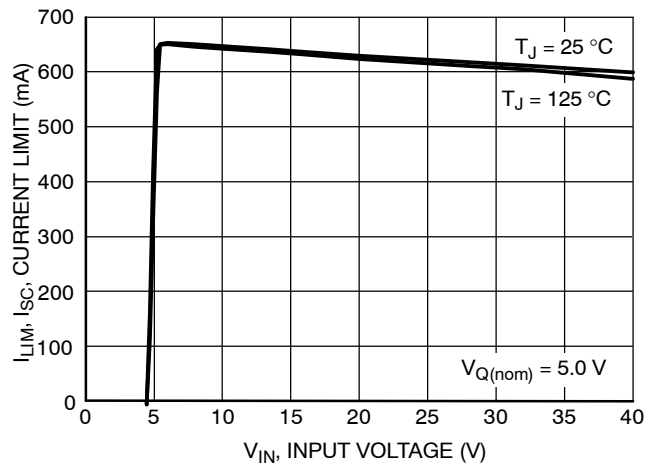


Figure 12. Output Current  $I_Q$  vs. Input Voltage  $V_{IN}$

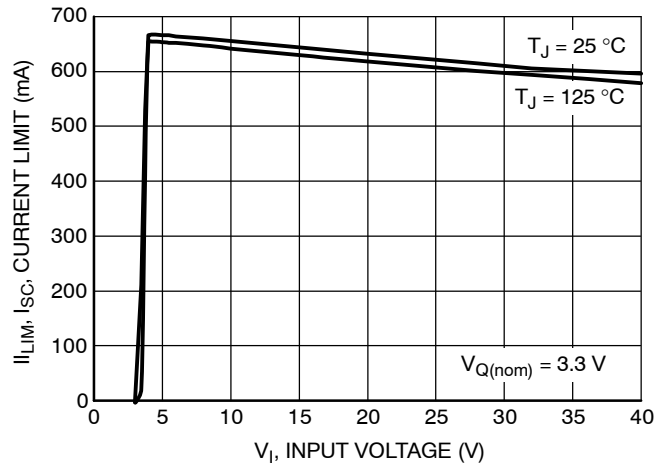


Figure 13. Output Current  $I_Q$  vs. Input Voltage  $V_{IN}$

TYPICAL PERFORMANCE CHARACTERISTICS

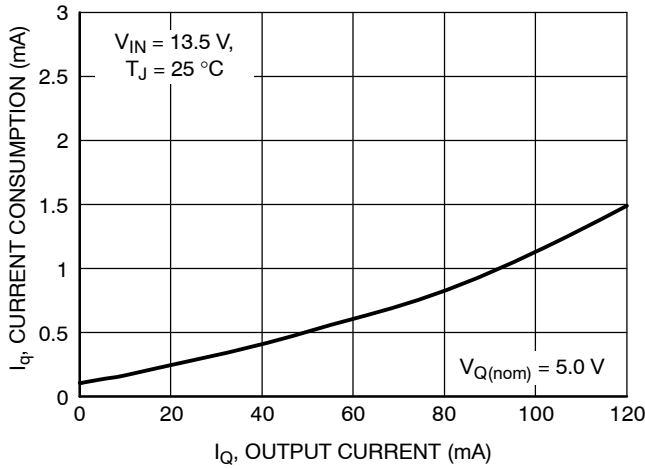


Figure 14. Current Consumption  $I_q$  vs. Output Current  $I_Q$

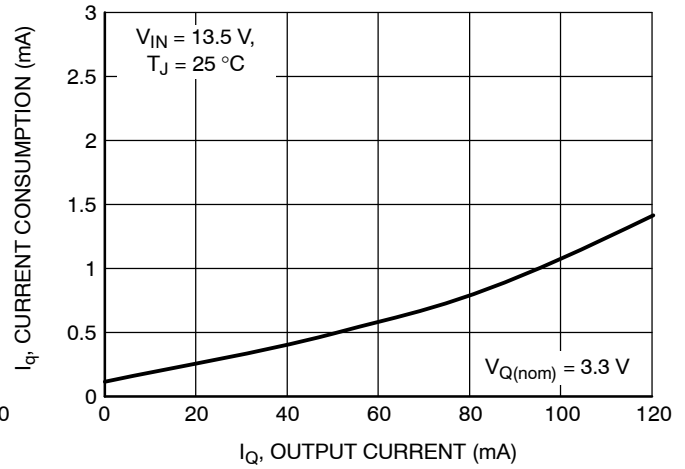


Figure 15. Current Consumption  $I_q$  vs. Output Current  $I_Q$

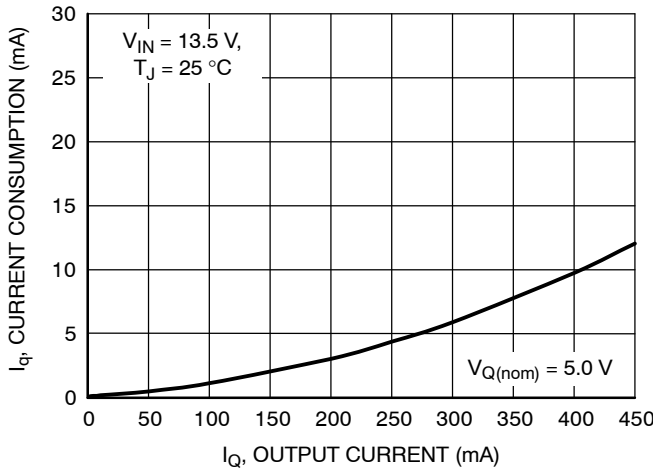


Figure 16. Current Consumption  $I_q$  vs. Output Current  $I_Q$

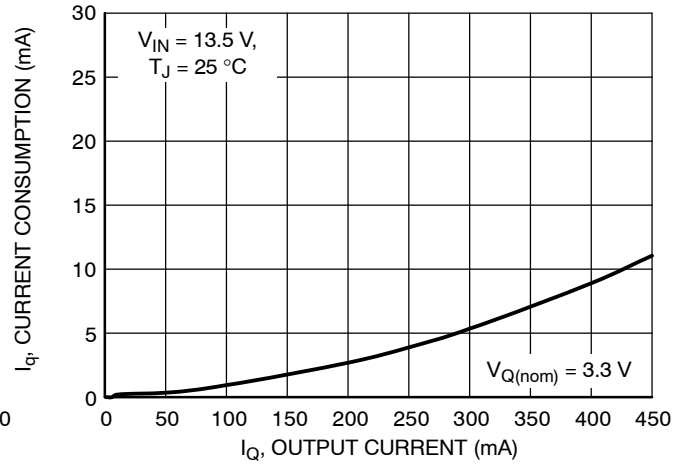


Figure 17. Current Consumption  $I_q$  vs. Output Current  $I_Q$

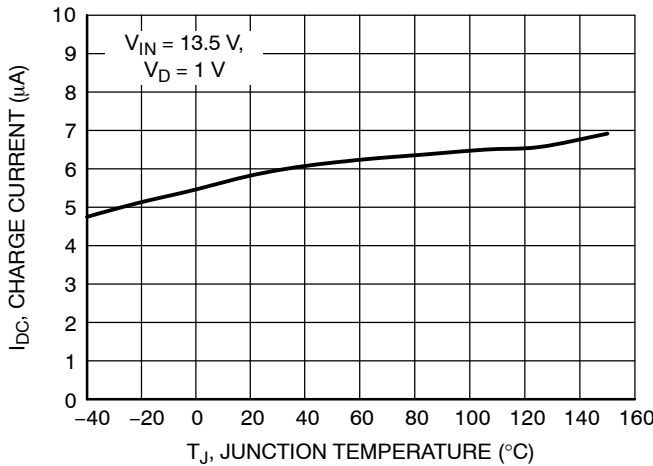


Figure 18. Charge Current  $I_{D,C}$  vs. Temperature  $T_J$

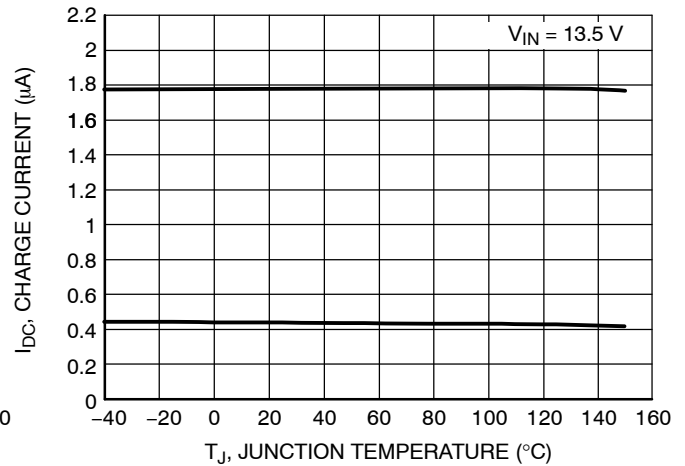


Figure 19. Delay Switching Threshold  $V_{DU}$ ,  $V_{DL}$  vs. Temperature  $T_J$

TYPICAL PERFORMANCE CHARACTERISTICS

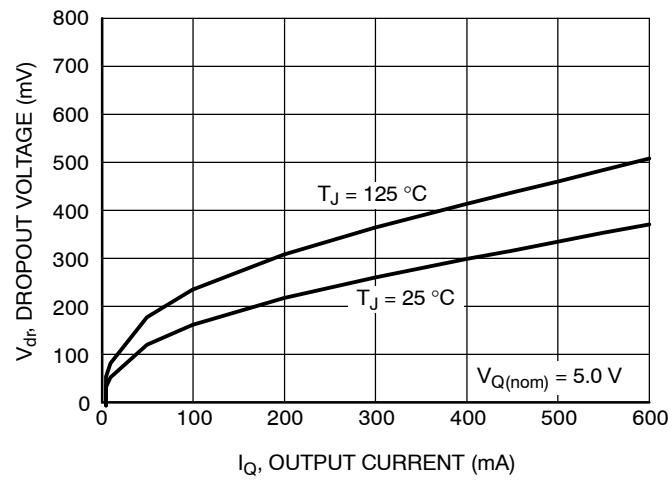


Figure 20. Drop Voltage  $V_{dr}$  vs. Output Current  $I_Q$

## APPLICATION INFORMATION

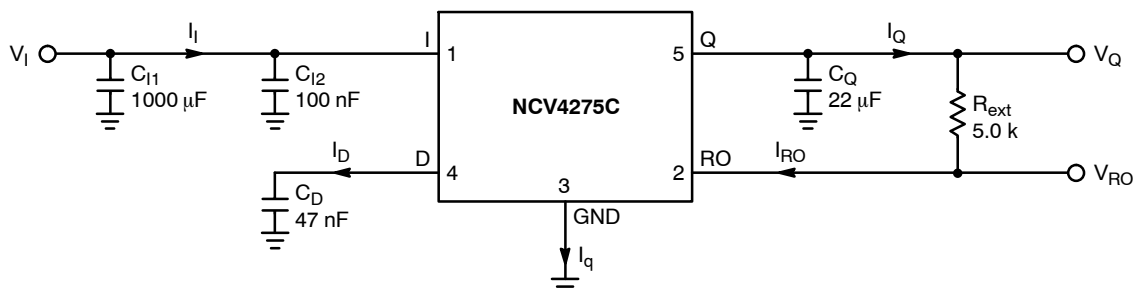


Figure 21. Test Circuit

### CIRCUIT DESCRIPTION

The NCV4275C is an integrated low dropout regulator that provides 5.0 V or 3.3 V, 450 mA protected output and a signal for power on reset. The regulation is provided by a PNP pass transistor controlled by an error amplifier with a bandgap reference, which gives it the lowest possible drop out voltage and best possible temperature stability. The output current capability is 450 mA, and the base drive quiescent current is controlled to prevent over saturation when the input voltage is low or when the output is overloaded. The regulator is protected by both current limit and thermal shutdown. Thermal shutdown occurs above 150 °C to protect the IC during overloads and extreme ambient temperatures. The delay time for the reset output is adjustable by selection of the timing capacitor. See Figure 21, Test Circuit, for circuit element nomenclature illustration.

### REGULATOR

The error amplifier compares the reference voltage to a sample of the output voltage ( $V_Q$ ) and drives the base of a PNP series pass transistor by a buffer. The reference is a bandgap design to give it a temperature-stable output. Saturation control of the PNP is a function of the load current and input voltage. Over saturation of the output power device is prevented, and quiescent current in the ground pin is minimized.

### REGULATOR STABILITY CONSIDERATIONS

The input capacitors ( $C_{I1}$  and  $C_{I2}$ ) are necessary to stabilize the input impedance to avoid voltage line influences. Using a resistor of approximately 1.0  $\Omega$  in series with  $C_{I2}$  can stop potential oscillations caused by stray inductance and capacitance.

The output capacitor helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability. The capacitor value and type should be based on cost, availability, size and temperature constraints. A tantalum, aluminum or ceramic capacitors can be used. The range of stability versus capacitance, load current and capacitive ESR is illustrated

in Figures 2 to 5. Minimum ESR for  $C_Q = 22 \mu\text{F}$  is native ESR of ceramic capacitors. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures ( $-25^\circ\text{C}$  to  $-40^\circ\text{C}$ ), both the capacitance and ESR of the capacitor will vary considerably. The capacitor manufacturer's data sheet usually provides this information.

The value for the output capacitor  $C_Q$  shown in Figure 21, Test Circuit, should work for most applications; however, it is not necessarily the optimized solution. Stability is guaranteed for  $C_Q \geq 22 \mu\text{F}$  and an  $\text{ESR} \leq 4.5 \Omega$  (5.0 V Version), 3.5  $\Omega$  (3.3 V Version). ESR characteristics were measured with ceramic capacitors and additional resistors to emulate ESR. Murata ceramic capacitors were used, GRM32ER71A226ME20 (22  $\mu\text{F}$ , 10 V, X7R, 1210), GRM31MR71E105KA01 (1  $\mu\text{F}$ , 25 V, X7R, 1206).

### RESET OUTPUT

The reset output is used as the power on indicator to the microcontroller. This signal indicates when the output voltage is suitable for reliable operation of the controller. It pulls low when the output is not considered to be ready. RO is pulled up to  $V_Q$  by an external resistor, typically 5.0 k $\Omega$  in value. The input and output conditions that control the Reset Output and the relative timing are illustrated in Figure 22, Reset Timing.

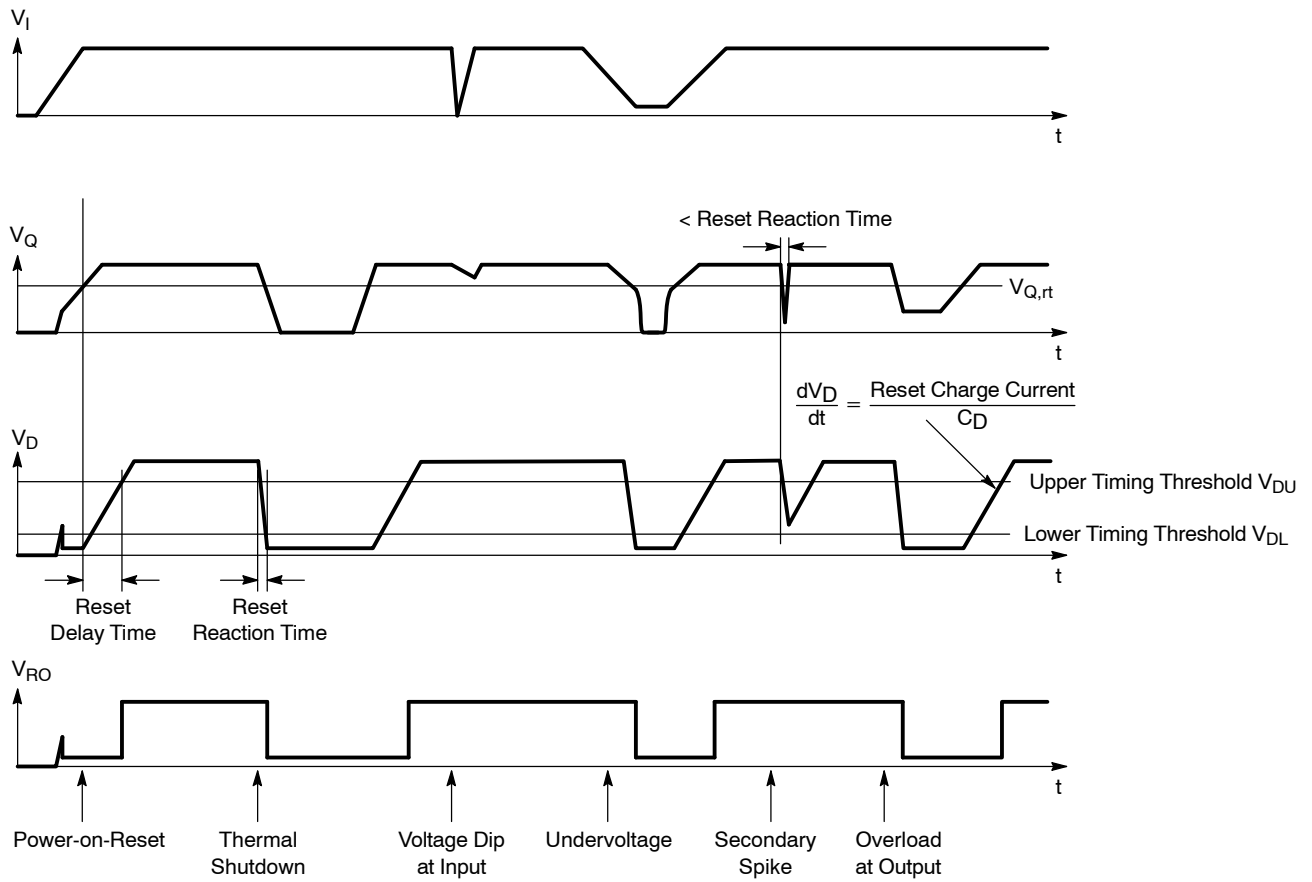
Output voltage regulation must be maintained for the delay time before the reset output signals a valid condition. The delay for the reset output is defined as the amount of time it takes the timing capacitor on the delay pin to charge from a residual voltage of 0.0 V to the upper timing threshold voltage  $V_{DU}$ . The charging current for this is  $I_{D,C}$  and D pin voltage in steady state is typically 2.4 V. By using typical IC parameters with a 47 nF capacitor on the D pin, the following time delay for 5.0 V regulator is derived:

$$t_{RD} = C_D V_{DU} / I_{D,C}$$

$$t_{RD} = 47 \text{ nF} (1.8 \text{ V}) / 5.5 \mu\text{A} = 15.4 \text{ ms}$$

Other time delays can be obtained by changing the capacitor value.

# NCV4275C



**Figure 22. Reset Timing**

### CALCULATING POWER DISSIPATION IN A SINGLE OUTPUT LINEAR REGULATOR

The maximum power dissipation for a single output regulator (Figure 23) is:

$$PD(max) = [V_{I(max)} - V_{Q(min)}] I_{Q(max)} + V_{I(max)} I_q \quad (1)$$

where

$V_{I(max)}$  is the maximum input voltage,

$V_{Q(min)}$  is the minimum output voltage,

$I_{Q(max)}$  is the maximum output current for the application,

$I_q$  is the quiescent current the regulator consumes at  $I_{Q(max)}$ .

Once the value of  $P_{D(max)}$  is known, the maximum permissible value of  $R_{\theta JA}$  can be calculated:

$$R_{\theta JA} = \frac{150^\circ\text{C} - T_A}{P_D} \quad (2)$$

The value of  $R_{\theta JA}$  can then be compared with those in the package section of the data sheet. Those packages with  $R_{\theta JA}$ 's less than the calculated value in Equation 2 will keep the die temperature below  $150^\circ\text{C}$ .

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heatsink will be required.

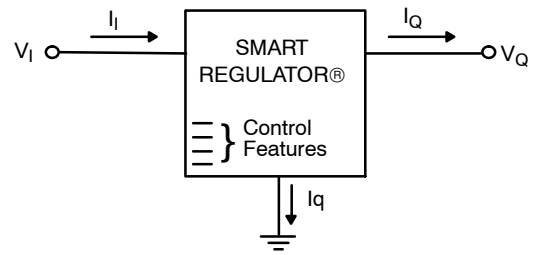


Figure 23. Single Output Regulator with Key Performance Parameters Labeled

### HEATSINKS

A heatsink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of  $R_{\theta JA}$ :

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA} \quad (3)$$

where

$R_{\theta JC}$  is the junction-to-case thermal resistance,

$R_{\theta CS}$  is the case-to-heatsink thermal resistance,

$R_{\theta SA}$  is the heatsink-to-ambient thermal resistance.

$R_{\theta JC}$  appears in the package section of the data sheet. Like  $R_{\theta JA}$ , it too is a function of package type.  $R_{\theta CS}$  and  $R_{\theta SA}$  are functions of the package type, heatsink and the interface between them. These values appear in heatsink data sheets of heatsink manufacturers.

Thermal, mounting, and heatsinking considerations are discussed in the **onsemi** application note AN1040/D.

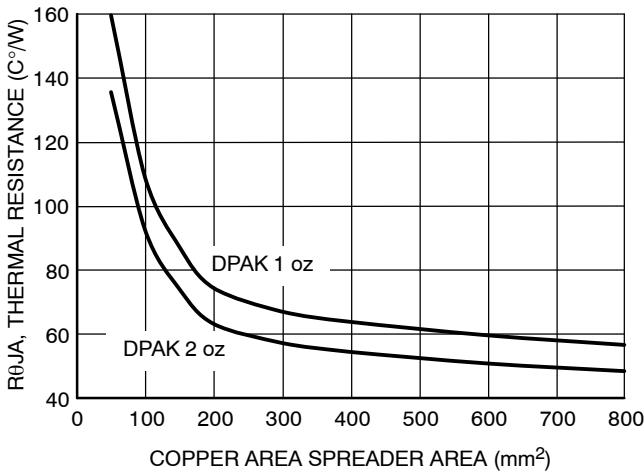


Figure 24.  $\theta_{JA}$  vs. Copper Spreader Area, DPAK 5-Lead

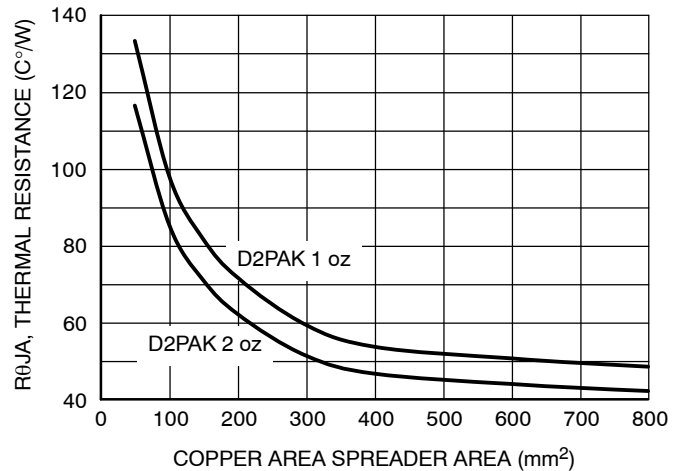


Figure 25.  $\theta_{JA}$  vs. Copper Spreader Area, D²PAK 5-Lead

# NCV4275C

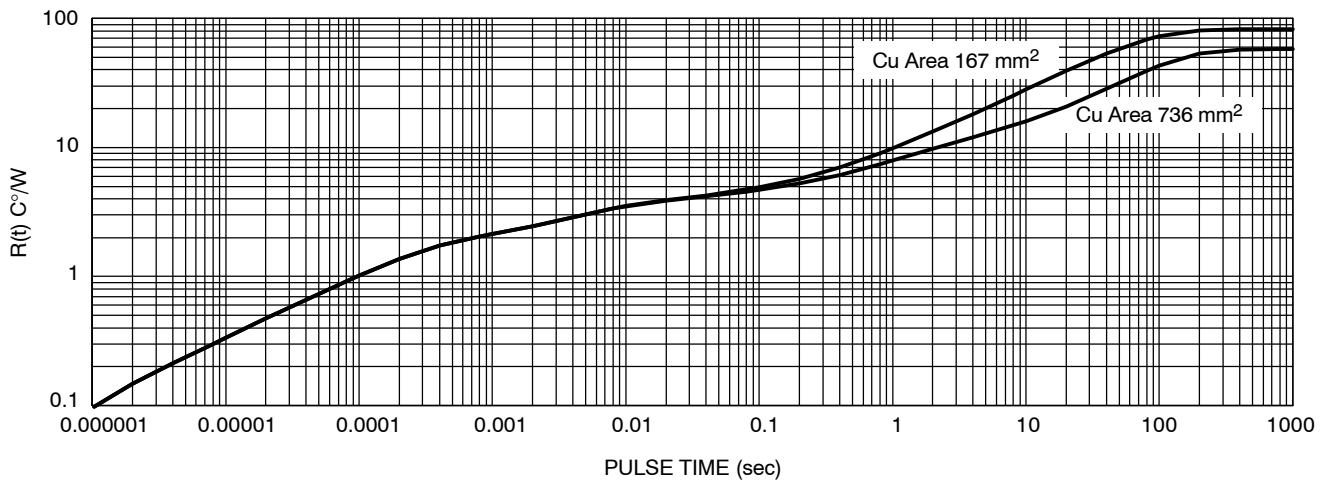


Figure 26. Single-Pulse Heating Curves, DPAK 5-Lead

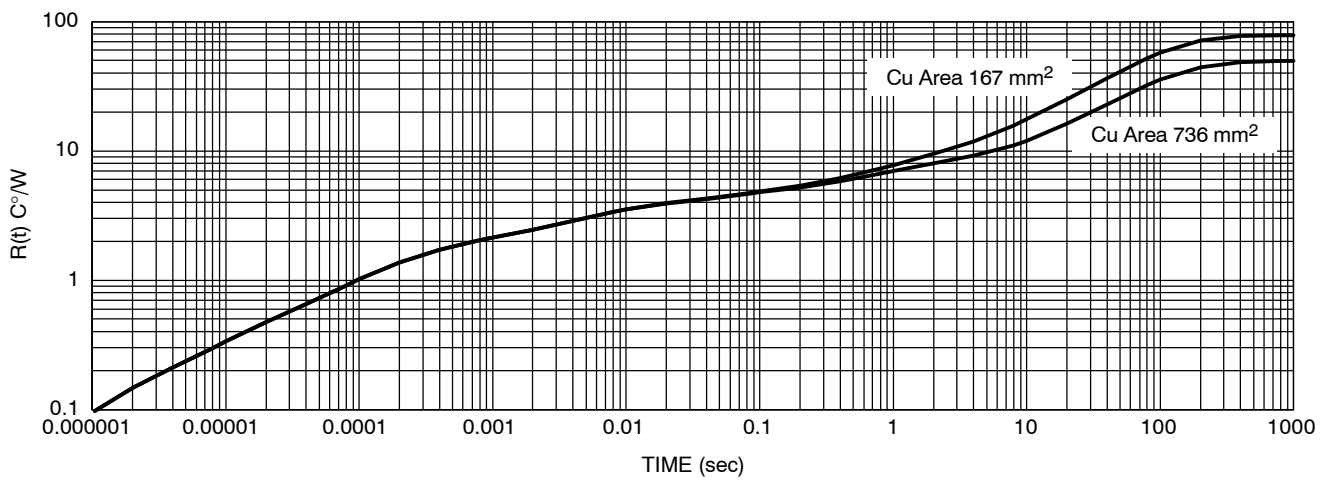


Figure 27. Single-Pulse Heating Curves, D<sup>2</sup>PAK 5-Lead

# NCV4275C

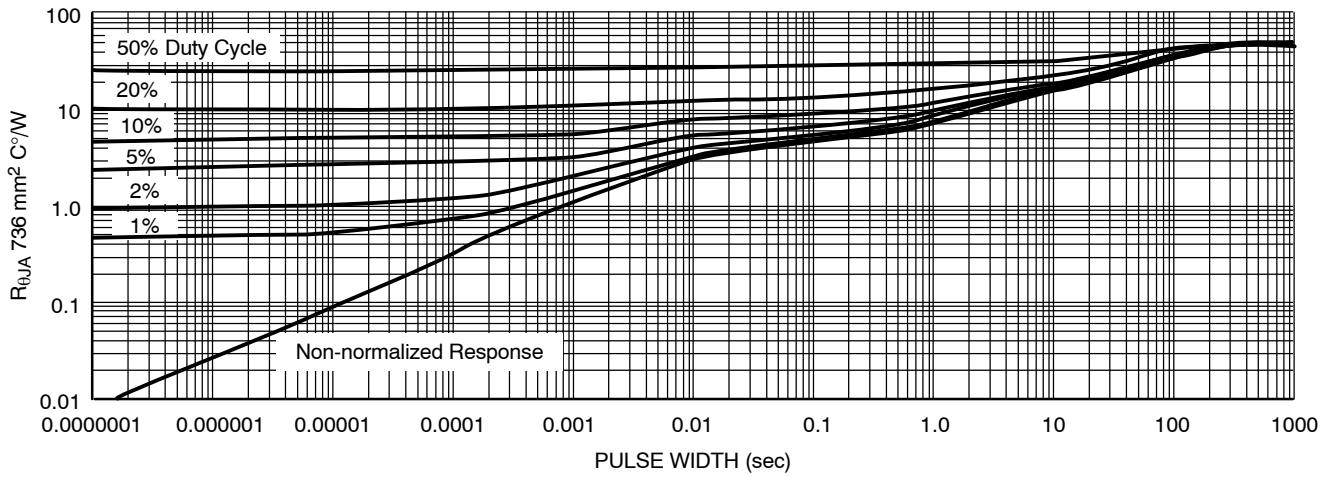


Figure 28. Duty Cycle for 1" Spreaders Boards, DPAK 5-Lead

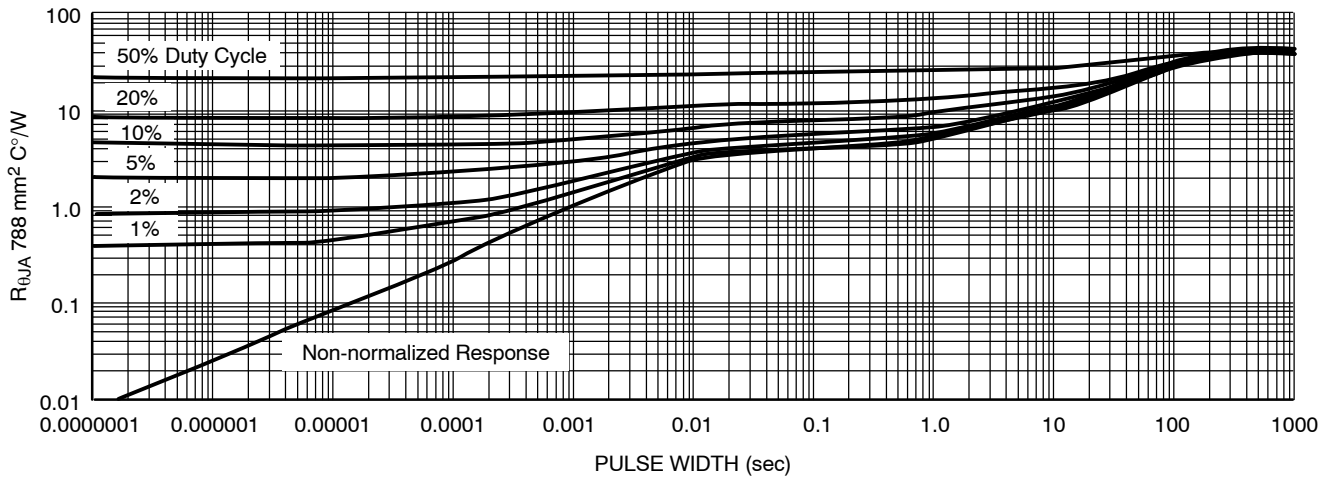


Figure 29. Duty Cycle for 1" Spreaders Boards, D²PAK 5-Lead

## ORDERING INFORMATION

| Device          | Output Voltage | Package                | Shipping†          |
|-----------------|----------------|------------------------|--------------------|
| NCV4275CDS50R4G | 5.0 V          | D2PAK 5-LEAD (Pb-Free) | 800 / Tape & Reel  |
| NCV4275CDT50RKG |                | DPAK-5 (Pb-Free)       | 2500 / Tape & Reel |
| NCV4275CDT33RKG | 3.3 V          | DPAK-5 (Pb-Free)       | 2500 / Tape & Reel |

## DISCONTINUED (Note 9)

|                 |       |                        |                   |
|-----------------|-------|------------------------|-------------------|
| NCV4275CDS33R4G | 3.3 V | D2PAK 5-LEAD (Pb-Free) | 800 / Tape & Reel |
|-----------------|-------|------------------------|-------------------|

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

9. **DISCONTINUED:** This device is not available. Please contact your **onsemi** representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).

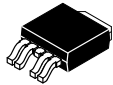


## NCV4275C

### REVISION HISTORY

| Revision | Description of Changes                                                                  | Date      |
|----------|-----------------------------------------------------------------------------------------|-----------|
| 0        | Initial production document version release.                                            | 1/21/2014 |
| 1        | Document rebranded to <b>onsemi</b> format. OPN NCV4275CDS33R4G marked as discontinued. | 2/10/2026 |

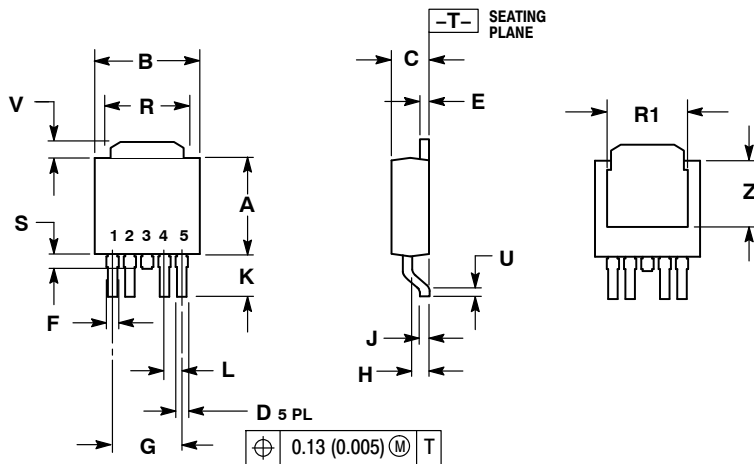




SCALE 1:1

**DPAK-5, CENTER LEAD CROP**  
CASE 175AA  
ISSUE B

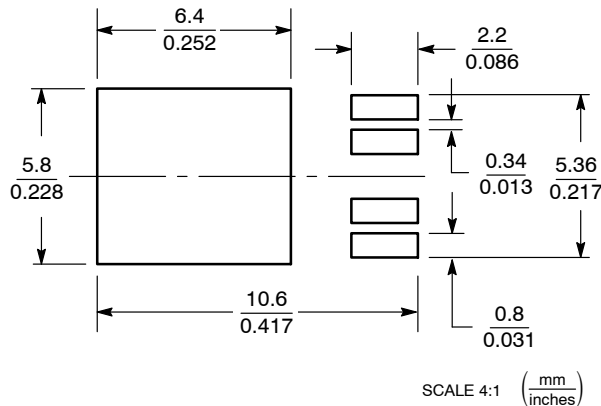
DATE 15 MAY 2014



## NOTES:

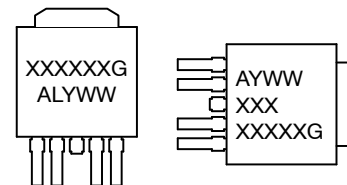
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES    |       | MILLIMETERS |      |
|-----|-----------|-------|-------------|------|
|     | MIN       | MAX   | MIN         | MAX  |
| A   | 0.235     | 0.245 | 5.97        | 6.22 |
| B   | 0.250     | 0.265 | 6.35        | 6.73 |
| C   | 0.086     | 0.094 | 2.19        | 2.38 |
| D   | 0.020     | 0.028 | 0.51        | 0.71 |
| E   | 0.018     | 0.023 | 0.46        | 0.58 |
| F   | 0.024     | 0.032 | 0.61        | 0.81 |
| G   | 0.180 BSC |       | 4.56 BSC    |      |
| H   | 0.034     | 0.040 | 0.87        | 1.01 |
| J   | 0.018     | 0.023 | 0.46        | 0.58 |
| K   | 0.102     | 0.114 | 2.60        | 2.89 |
| L   | 0.045 BSC |       | 1.14 BSC    |      |
| R   | 0.170     | 0.190 | 4.32        | 4.83 |
| R1  | 0.185     | 0.210 | 4.70        | 5.33 |
| S   | 0.025     | 0.040 | 0.63        | 1.01 |
| U   | 0.020     | ---   | 0.51        | ---  |
| V   | 0.035     | 0.050 | 0.89        | 1.27 |
| Z   | 0.155     | 0.170 | 3.93        | 4.32 |

**RECOMMENDED  
SOLDERING FOOTPRINT\***


SCALE 4:1 (mm / inches)

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, [SOLDERM/D](#).

**GENERIC  
MARKING DIAGRAMS\***


IC

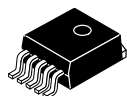
Discrete

XXXXXX = Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

|                         |                                |                                                                                                                                                                                  |
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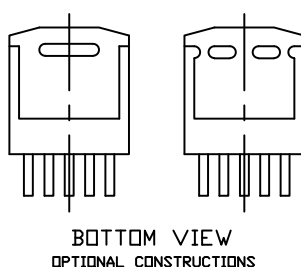
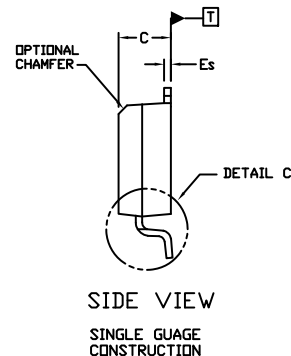
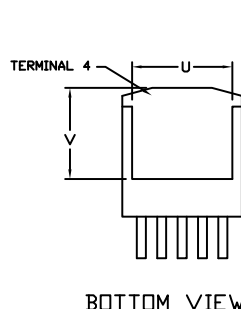
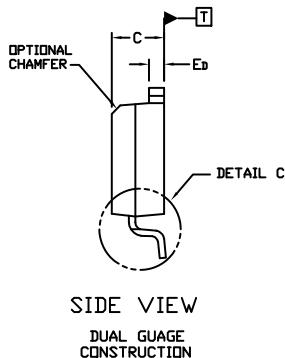
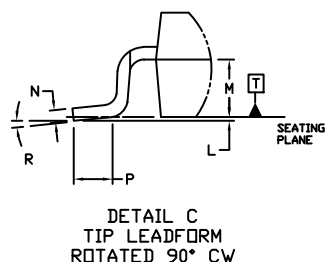
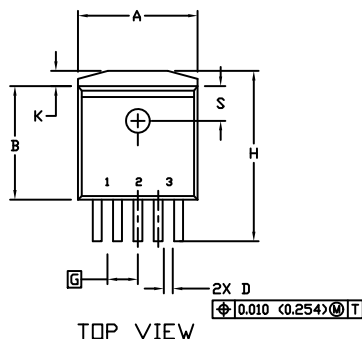
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SCALE 1:1

**D<sup>2</sup>PAK 5-LEAD**  
**CASE 936A-02**  
**ISSUE E**

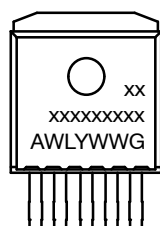
DATE 28 JUL 2021



## NOTES:

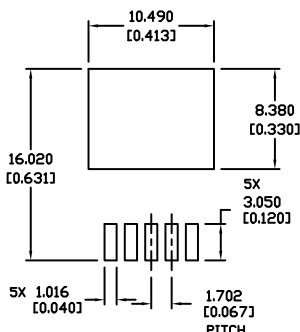
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCHES
- TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.
- DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 4.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

| DIM | INCHES |       | MILLIMETERS |        |
|-----|--------|-------|-------------|--------|
|     | MIN.   | MAX.  | MIN.        | MAX.   |
| A   | 0.396  | 0.403 | 9.804       | 10.236 |
| B   | 0.356  | 0.368 | 9.042       | 9.347  |
| C   | 0.170  | 0.180 | 4.318       | 4.572  |
| D   | 0.026  | 0.036 | 0.660       | 0.914  |
| Ed  | 0.045  | 0.055 | 1.143       | 1.397  |
| Es  | 0.018  | 0.026 | 0.457       | 0.660  |
| G   | 0.067  | BSC   | 1.702       | BSC    |
| H   | 0.539  | 0.579 | 13.691      | 14.707 |
| K   | 0.050  | REF   | 1.270       | REF    |
| L   | 0.000  | 0.010 | 0.000       | 0.254  |
| M   | 0.088  | 0.102 | 2.235       | 2.591  |
| N   | 0.018  | 0.026 | 0.457       | 0.660  |
| P   | 0.058  | 0.078 | 1.473       | 1.981  |
| R   | 0°     | 8°    | 0°          | 8°     |
| S   | 0.116  | REF   | 2.946       | REF    |
| U   | 0.200  | MIN   | 5.080       | MIN    |
| V   | 0.250  | MIN   | 6.350       | MIN    |

**GENERIC  
MARKING DIAGRAM\***


xxxxxx = Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.


**RECOMMENDED  
MOUNTING FOOTPRINT \***

\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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